TOSHIBA MOS DIGITAL INTEGRATED CIRCUIT SILICON GATE CMOS

1.048.576-WORD BY 18-BIT SYNCHRONOUS NO-TURNAROUND STATIC RAM **DESCRIPTION**

The TC55VD1618FFI is a synchronous static random access memory(SRAM) organized as 1,048,576 words by 18 bits. NtRAMTM(no-turnaround) SRAM offers high bandwidth by eliminating dead cycles during the transition from a read to a write and vice versa. All inputs except Output Enable OE and the ADV are synchronized with the rising edge of the CLK input. A Read operation is initiated of the ADV address. are synchronized with the rising edge of the CLK input. A Read operation is initiated by the ADV Address Advanced Input signal; the input from the address pins and all control pins except the OE and ZZ pins are loaded into the internal registers on the rising edge of CLK in the cycle in which ADV is asserted. The output data is available two clock cycles later. Write operations are internally self-timed and are initiated by the rising edge of CLK in the cycle in which ADV is asserted. The input from the address pins and all control pins except the OE and ZZ pins are loaded into the internal registers on the rising edge of CLK in the cycle in which ADV is asserted. Input data is loaded in the third cycle after the cycle in which ADV is asserted. Byte Write Enables(BW1 to BW2) allow from one to two Byte Write operations to be performed. A 2-bit burst address counter and control logic are integrated into this SRAM. The TC55VD1618FFI uses a single power supply (3.3V) or dual power supplies(3.3V for core and 2.5V for output buffer) and is available in a 100-pin low-profile plastic QFP(LQFP). The TC55VD1618FFI guarantees -40° to 85°C operating temperature so it is suitable for use in wide operating temperature system. use in wide operating temperature system.

FEATURES

Organized as 1,048,576 words by 18 bits

Fast cycle time of 6.6 ns minimum (150 MHz maximum)
Fast access time of 3.8 ns maximum (from clock edge to data output)

No-turnaround operation with pipeline data output

2-bit burst address counter (support for interleaved or linear burst sequences)

Synchronous self-timed Write

Byte Write control Snooze mode pin (ZZ) for power down

LVTTL-compatible interface

Single power supply(3.3 V) or Dual power supplies(3.3 V for core and 2.5 V for output buffer)
Available in 100-pin LQFP package (LQFP100-P-1420-0.65B; pitch:0.65 mm, height:1.6 mm, weight:0.91 grams(typical))

PIN ASSIGNMENT (TOP VIEW)

NECONO SECULO SE 99 97 95 93 91 89 87 85 83 81 100 98 96 94 92 90 88 86 84 82 32 34 36 38 40 42 44 46 48 5051 H NC

PIN NAMES

| CLK Clock Input A0 to A19 Address Inputs CE, CE2, CE2 Chip Enable Inputs OE Output Enable WE Write Enable Input BW1 to BW2 Byte Write Enable ADV Address Advance Input CKE Clock Enable ZZ Snooze Input I/O1 to I/O16 Data Inputs/Outputs I/OP1 to I/OP2 Parity Data Inputs/Outputs MODE Mode Select Input NC Not Connected NU Not Usable VDD Power Supply for Core | FIIN INAIVILS | |
|---|--------------------------------------|--------------------------------|
| CE, CE2, CE2 Chip Enable Inputs OE Output Enable WE Write Enable Input BW1 to BW2 Byte Write Enable ADV Address Advance Input CKE Clock Enable ZZ Snooze Input I/O1 to I/O16 Data Inputs/Outputs I/OP1 to I/OP2 Parity Data Inputs/Outputs MODE Mode Select Input NC Not Connected NU Not Usable | CLK | Clock Input |
| OE | A0 to A19 | Address Inputs |
| WE Write Enable Input | $\overline{CE}, \overline{CE2}, CE2$ | Chip Enable Inputs |
| BW1 to BW2 Byte Write Enable ADV Address Advance Input CKE Clock Enable ZZ Snooze Input I/O1 to I/O16 Data Inputs/Outputs I/OP1 to I/OP2 Parity Data Inputs/Outputs MODE Mode Select Input NC Not Connected NU Not Usable | ŌĒ | Output Enable |
| ADV Address Advance Input CKE Clock Enable ZZ Snooze Input I/O1 to I/O16 Data Inputs/Outputs I/OP1 to I/OP2 Parity Data Inputs/Outputs MODE Mode Select Input NC Not Connected NU Not Usable | WE | Write Enable Input |
| ZZ Snooze Input I/O1 to I/O16 Data Inputs/Outputs I/OP1 to I/OP2 Parity Data Inputs/Outputs MODE Mode Select Input NC Not Connected NU Not Usable | BW1 to BW2 | Byte Write Enable |
| ZZ Snooze Input I/O1 to I/O16 Data Inputs/Outputs I/OP1 to I/OP2 Parity Data Inputs/Outputs MODE Mode Select Input NC Not Connected NU Not Usable | ADV | Address Advance Input |
| I/O1 to I/O16 Data Inputs/Outputs I/OP1 to I/OP2 Parity Data Inputs/Outputs MODE Mode Select Input NC Not Connected NU Not Usable | CKE | Clock Enable |
| I/OP1 to I/OP2 Parity Data Inputs/Outputs MODE Mode Select Input NC Not Connected NU Not Usable | ZZ | Snooze Input |
| MODE Mode Select Input NC Not Connected NU Not Usable | I/O1 to I/O16 | Data Inputs/Outputs |
| NC Not Connected NU Not Usable | I/OP1 to I/OP2 | Parity Data Inputs/Outputs |
| NU Not Usable | MODE | Mode Select Input |
| | NC | Not Connected |
| V _{DD} Power Supply for Core | NU | Not Usable |
| | V_{DD} | Power Supply for Core |
| | V_{DDQ} | Power Supply for Output Buffer |
| V _{SS} Ground for Core | | Ground for Core |
| V _{SSQ} Ground for Output Buffer | V _{SSQ} | Ground for Output Buffer |

Note: NtRAMTM and No-Turnaround Random Access Memory are trademarks of Samsung Electronics Co., Ltd..

000707EBA2

OTOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of safety in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of such TOSHIBA products could cause loss of human life, bodily injury or damage to property.

In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability Handbook" etc.

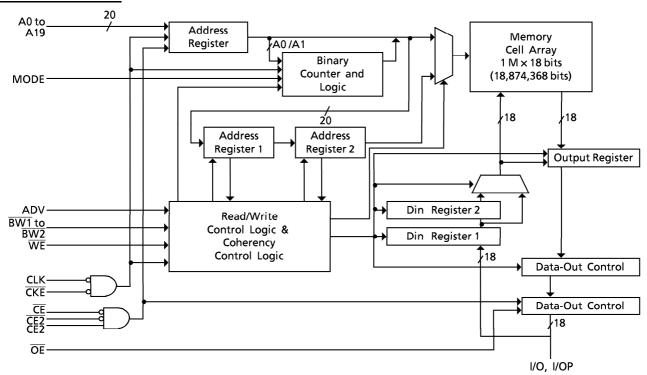
The TOSHIBA products listed in this document are intended for usage in general electronics applications (computer, personal equipment, office equipment, measuring equipment, industrial robotics, domestic appliances, etc.). These TOSHIBA products are neither intended nor warranted for usage in equipment that requires extraordinarily high quality and/or reliability or a malfunction or failure of which may cause loss of human life or bodily injury ("Unintended Usage"). Unintended Usage include atomic energy control instruments, airplane or spaceship instruments, transportation instruments, transfic signal instruments, combustion control instruments, all types of safety devices, etc.. Unintended Usage of TOSHIBA products listed in this document shall be made at the customer's own risk.

The products described in this document are subject to the foreign exchange and foreign trade laws.

The information contained herein is presented only as a guide for the applications of our products. No responsibility is assumed by TOSHIBA CORPORATION for any infringements of intellectual property or other rights of TOSHIBA CORPORATION or others.

The

BLOCK DIAGRAM



PIN DESCRIPTIONS

| PIN NUMBER | SYMBOL | TYPE | DESCRIPTION |
|--|------------|-------------------------|---|
| 89 | CLK | Input (NA) | Clock Input All synchronous input signals are registered on the rising edge of CLK. When the chip is enabled, address inputs and control pins except for OE and ZZ must meet the specified setup and hold times with respect to the CLK rising edge. |
| 37, 36, 35, 34, 33, 32, 100, 99, 82, 81, 44, 45, 46, 47, 48, 49, 50, 83, 80, 84 | A0 to A19 | Input (synchronous) | Address Inputs These address inputs are registered on the rising edge of CLK. When the chip is enabled, address inputs must meet the specified setup and hold times with respect to the CLK rising edge. |
| 98 | CE | Input (synchronous) | Chip Enable Input This active-Low signal controls the chip status (enabled or disabled). It is sampled only when a new external address is loaded. |
| 92 | CF2 | Input (synchronous) | Chip Enable Input This active-Low signal controls the chip status (enabled or disabled). It is sampled only when a new external address is loaded. |
| 97 | CE2 | Input (synchronous) | Chip Enable Input This active-high signal controls the chip status (enabled or disabled). It is sampled only when a new external address is loaded. |
| 86 | ŌĒ | Input (asynchronous) | Output Enable Input This active-Low signal controls all 36 bits of the I/O output buffer. |
| 88 | WE | Input (synchronous) | Write Enable Input This active-Low input controls Read/Write operations. |
| 93, 94 | BW1 to BW2 | Input (synchronous) | Byte Write Enable These active-Low inputs control Byte Write operations when a Write cycle is active. A Byte Write pin controls I/O pins as follows. BW1:I/O1 to I/O8, I/OP1 BW2:I/O9 to I/O16, I/OP2 |
| 85 | ADV | Input (synchronous) | Address Advance Input This is used to load the internal registers with the input from the address and control signals when it is Low on the rising edge of CLK. When it is High, the internal burst address counter is incremented. The external address inputs are ignored when this signal is High. |
| 87 | CKE | Input (synchronous) | Clock Enable When High, CLK input is ignored and outputs retain the same state. |

| PIN NUMBER | SYMBOL | TYPE | DESCRIPTION |
|---|--------------------|-------------------------|---|
| 64 | ZZ | Input (asynchronous) | Snooze Input This active-High signal is used to place the device into Sleep Mode (Low-Power Standby Mode). When Low, the device remains in the Active state. When High, the device goes into the Sleep state and memory data is retained. After this signal has been de-asserted, the device will wake up when a read or write operation is initiated by ADV. |
| 58, 59, 62, 63, 68, 69, 72, 73, 8, 9, 12, 13, 18, 19, 22, 23 | I/O1 to I/O16 | I/O (synchronous) | Data Input/Output |
| 74, 24 | I/OP1 to I/OP2 | I/O (synchronous) | Parity Data Input/Output |
| 31 | MODE | Input (synchronous) | Mode Select Input This signal selects the burst sequence. When High, the burst sequence is interleaved. When Low, it is linear. |
| 1, 2, 3, 6, 7, 25, 28, 29, 30, 39, 42, 43, 51, 52, 53, 56, 57, 75, 78, 79, 95, 96 | NC | NC | Not Connected |
| 38 | NU | Input (asynchronous) | Not Usable |
| 14, 15, 16, 41, 65, 66, 91 | V _{DD} | Supply | Power Supply for Core |
| 4, 11, 20, 27, 54, 61, 70, 77 | V_{DDQ} | Supply | Power Supply for Output Buffers |
| 17, 40, 67, 90 | V _{SS} | Ground | Ground for Core |
| 5, 10, 21, 26, 55, 60, 71, 76 | V _{SSQ} | Ground | Ground for Output Buffers |

OPERATING MODE

(1) Synchronous Input Truth Table

| OPERATION | WE | ADV | CE | BW | Addr. Used | CKE | ZZ | I/O (2 cycles later) |
|-------------------------------|----|-----|----------|----|------------|-----|----|-------------------------|
| Read (begin burst) | Н | L | Select | × | External | L | L | Output |
| Read (continue burst) | × | Н | × | × | Internal | L | L | Output |
| Write (begin burst) | L | L | Select | L | External | L | L | Input |
| Write (continue burst) | × | Н | × | L | Internal | L | L | Input |
| NOP/Write Abort (begin burst) | L | L | Select | Н | × | L | L | Hi-Z |
| Write Abort (continue burst) | × | Н | × | Н | Internal | L | L | Hi-Z |
| Deselected | × | L | Deselect | × | × | L | L | Hi-Z |
| Deselect Continue (Note 2) | × | Н | × | × | × | L | L | Hi-Z |
| Ignore Clock Edge (Note 3) | × | × | × | × | × | Н | L | Previous value |
| Snooze | × | × | × | × | × | × | Н | Hi-Z |

Notes: 1. H means logical High and L means logical Low. X means Don't care.

- 2. A Deselect Continue cycle can only be entered if a Deselect cycle is executed before it.
- 3. When the Ignore Clock Edge command is asserted during a Read operation, the output data for the previous cycle still appear on the I/O pins. When the command is asserted during a Write operation, the I/O pins remain at Hi-Z and the Write operation is not executed.
- 4. All synchronous Inputs must exhibit adequate setup and hold times either side of the rising edge of the CLK pin.
- 5. ZZ input is asynchronous, but is included in this table.

(2) Write Enable Truth Table

| OPERATION | WE | BW1 | BW2 | I/O1 to I/O8 I/OP1 | I/O9 to I/O16 I/OP2 |
|-----------|----|-----|-----|-----------------------|------------------------|
| Read | Н | × | × | Output | Output |
| Write | L | L | L | Input | Input |
| | L | L | Н | Input | Hi-Z |
| | L | Н | L | Hi-Z | Input |
| | L | Н | Н | Hi-Z | Hi-Z |

Notes: 1. H means logical High and L means logical Low. X means Don't care.

2. The status for I/O pins described in this column appears two clock cycles after the cycle in which the Read or Write command is asserted.

(3) Asynchronous Inputs Truth Table

| OPERATION | ŌĒ | ZZ | 1/0 |
|---------------------|----|----|-----------|
| Read | L | L | Dout |
| | Н | L | Hi-Z |
| Write | × | L | Din, Hi-Z |
| Stop clock (Note 2) | Н | L | Hi-Z |
| , | L | L | Dout |
| Snooze (Note 3) | × | Н | Hi-Z |

Notes: 1. H means logical High and L means logical Low. X means Don't care.

- 2. The Stop CLK Mode achieves Low-Power Standby by stopping the input clock.
- 3. The Snooze Mode achieves Low-Power Standby by asserting the ZZ pin.
- 4. The cycle immediately prior to a snooze brought about by the ZZ pin must be a Read Mode or Deselect Mode cycle.
- 5. Memory data is retained during Snooze Mode cycles.

(4) Burst Sequence

| MODE PIN | BURST OPERATION |
|----------|-------------------------|
| L | Linear burst order |
| H or NC | Interleaved burst order |

a) Linear Burst Sequence (MODE input=V_{SS})

Bit Order: A_{19} , A_1 , A_0

| 1st Address (external) | 2nd Address (internal) | 3rd Address (internal) | 4th Address (internal) |
|---------------------------|---------------------------|---------------------------|---------------------------|
| XX ····· XX00 | XX ····· XX01 | XX ····· XX10 | XX ····· XX11 |
| XX ····· XX01 | XX ····· XX10 | XX ····· XX11 | xx xx00 |
| XX ····· XX10 | XX ····· XX11 | XX ····· XX00 | XX ····· XX01 |
| XX ····· XX11 | XX ····· XX00 | XX ····· XX01 | XX ····· XX10 |

b) Interleaved Burst Sequence (MODE input= V_{DD} or NC)

Bit Order: A_{19} A_1 , A_0

| 1st Address (external) | 2nd Address (internal) | 3rd Address (internal) | 4th Address (internal) |
|---------------------------|---------------------------|---------------------------|---------------------------|
| XX ····· XX00 | XX ····· XX01 | XX ····· XX10 | XX ····· XX11 |
| XX ····· XX01 | xx xx00 | XX ····· XX11 | XX ····· XX10 |
| XX ····· XX10 | XX ····· XX11 | XX ····· XX00 | XX ····· XX01 |
| XX ····· XX11 | XX ····· XX10 | XX ····· XX01 | XX ····· XX00 |

DEVICE OPERATION

(1) Read Operation

| CYCLE | ADDRESS | WE | BW | ADV | CE | ŌĒ | CKE | I/O | OPERATION |
|-------|---------|----|----|-----|----|----|-----|-----|-------------------------|
| n | A0 | Н | × | L | L | × | L | × | Address & control valid |
| n + 1 | × | × | × | × | × | × | L | × | |
| n + 2 | × | × | × | × | × | L | L | Q0 | Read out A0 |

Note 1: H means logical High and L means logical Low. X means Don't care. Q is data output.

(2) Burst Read Operation

| CYCLE | ADDRESS | WE | BW | ADV | CE | ŌĒ | CKE | 1/0 | OPERATION |
|--------|---------|----|----|-----|----|----|-----|--------|-------------------------|
| n | A0 | Н | × | L | L | × | L | × | Address & control valid |
| n + 1 | × | × | × | Н | × | × | L | × | |
| n + 2 | × | × | × | Н | × | L | L | Q0 | Read out A0 |
| n + 3 | × | × | × | Н | × | L | L | Q0 + 1 | Read out A0 + 1 |
| n + 4 | × | × | × | Н | × | L | L | Q0 + 2 | Read out A0+2 |
| n + 5 | A1 | Н | × | L | L | L | L | Q0 + 3 | Read out A0+3 |
| n + 6 | × | × | × | Н | × | L | L | Q0 | Read out A0 |
| n + 7 | × | × | × | Н | × | L | L | Q1 | Read out A1 |
| n + 8 | A2 | Н | × | L | L | L | L | Q1 + 1 | Read out A1 + 1 |
| n + 9 | А3 | Н | × | L | L | L | L | Q1 + 2 | Read out A1 + 2 |
| n + 10 | × | × | × | × | × | L | L | Q2 | Read out A2 |

Note 1: H means logical High and L means logical Low. X means Don't care. Q is data output.

(3) Write Operation

| CYCLE | ADDRESS | WE | BW | ADV | CE | ŌĒ | CKE | 1/0 | OPERATION |
|-------|---------|----|----|-----|----|----|-----|-----|-------------------------|
| n | A0 | L | L | L | L | × | L | × | Address & control valid |
| n + 1 | × | × | × | × | × | × | | × | |
| n + 2 | × | × | × | × | × | × | L | D0 | Write to A0 |

Note 1: H means logical High and L means logical Low. X means Don't care. D is data input.

(4) Burst Write Operation

| CYCLE | ADDRESS | WE | BW | ADV | CE | ŌĒ | CKE | 1/0 | OPERATION |
|--------|---------|----|----|-----|----|----|-----|--------|-------------------------|
| n | A0 | L | L | L | L | × | L | × | Address & control valid |
| n + 1 | × | × | L | Н | × | × | L | × | |
| n + 2 | × | × | L | Н | × | × | L | D0 | Write A0 |
| n + 3 | × | × | L | Н | × | × | L | D0 + 1 | Write A0 + 1 |
| n + 4 | × | × | L | Н | × | × | L | D0 + 2 | Write A0 + 2 |
| n + 5 | A1 | L | L | L | L | × | L | D0 + 3 | Write A0+3 |
| n + 6 | × | × | L | Н | × | × | L | D0 | Write A0 |
| n + 7 | × | × | L | Н | × | × | L | D1 | Write A1 |
| n + 8 | A2 | L | L | L | L | × | L | D1+1 | Write A1 + 1 |
| n + 9 | A3 | L | L | L | L | × | L | D1 + 2 | Write A1 + 2 |
| n + 10 | × | × | L | × | × | × | L | D2 | Write A2 |

Note 1: H means logical High and L means logical Low. X means Don't care. D is data input.

(5) Read Operation with Clock Enable

| CYCLE | ADDRESS | WE | BW | ADV | CE | ŌĒ | CKE | 1/0 | OPERATION |
|-------|---------|----|----|-----|----|----|-----|-----|----------------------------|
| n | A0 | Н | × | L | L | × | L | × | Address & control valid |
| n + 1 | × | × | × | × | × | × | Н | × | Ignore cycle |
| n + 2 | A1 | Н | × | L | L | × | L | × | Address & control valid |
| n + 3 | × | × | × | × | × | L | Н | Q0 | Ignore clock, Q0 is on bus |
| n + 4 | × | × | × | × | × | L | Н | Q0 | Ignore clock, Q0 is on bus |
| n + 5 | A2 | Н | × | L | L | L | L | Q0 | Read out A0 |
| n + 6 | А3 | Н | × | L | L | L | L | Q1 | Read out A1 |
| n + 7 | × | × | × | × | × | L | L | Q2 | Read out A2 |

Note 1: H means logical High and L means logical Low. X means Don't care. Q is data output.

(6) Write Operation with Clock Enable

| CYCLE | ADDRESS | WE | BW | ADV | CE | ŌĒ | CKE | 1/0 | OPERATION |
|-------|---------|----|----|-----|----|----|-----|-----|-------------------------|
| n | A0 | L | L | L | L | × | L | × | Address & control valid |
| n + 1 | × | × | × | × | × | × | Н | × | Ignore clock |
| n + 2 | A1 | L | L | L | L | × | L | × | Address & control valid |
| n + 3 | × | × | × | × | × | × | Н | × | Ignore clock |
| n + 4 | × | × | × | × | × | × | Н | × | Ignore clock |
| n + 5 | A2 | L | L | L | L | × | L | D0 | Address & control valid |
| n + 6 | А3 | L | L | L | L | × | L | D1 | Write A1 |
| n + 7 | × | × | × | × | × | × | L | D2 | Write A2 |

Note 1: H means logical High and L means logical Low. X means Don't care. D is data input.

(7) Read Operation with Chip Enable

| CYCLE | ADDRESS | WE | BW | ADV | CE | ŌĒ | CKE | 1/0 | OPERATION |
|-------|---------|----|----|-----|----|----|-----|-----|-------------------------|
| n | A0 | Н | × | L | L | × | L | × | Address & control valid |
| n + 1 | × | × | × | L | Н | × | L | × | Deselect |
| n + 2 | A1 | Н | × | L | L | L | L | Q0 | Read A0 |
| n + 3 | × | × | × | L | Н | × | L | Z | Deselect |
| n + 4 | × | × | × | L | Н | L | L | Q1 | Read A1 |
| n + 5 | A2 | Н | × | L | L | × | L | Z | Deselect |
| n + 6 | × | × | × | L | Н | × | L | Z | Deselect |
| n + 7 | × | × | × | L | Н | L | L | Q2 | Read A2 |

Note 1: H means logical High and L means logical Low. X means Don't care. Q is data output. Z means Hi-Z.

(8) Write Operation with Chip Enable

| CYCLE | ADDRESS | WE | BW | ADV | CE | ŌĒ | CKE | 1/0 | OPERATION |
|-------|---------|----|----|-----|----|----|-----|-----|-------------------------|
| n | A0 | L | L | L | L | × | L | × | Address & control valid |
| n + 1 | × | × | × | L | Н | × | L | × | Deselect |
| n + 2 | A1 | ٦ | L | L | L | × | L | D0 | Write A0 |
| n + 3 | × | × | × | L | Н | × | L | Z | Deselect |
| n + 4 | × | × | × | L | Н | × | L | D1 | Write A1 |
| n + 5 | A2 | L | L | L | L | × | L | Z | Deselect |
| n + 6 | × | × | × | L | Н | × | L | Z | Deselect |
| n + 7 | × | × | × | L | Н | × | L | D2 | Write A2 |

Note 1: H means logical High and L means logical Low. \times means Don't care. D is data input. Z means Hi-Z.

ABSOLUTE MAXIMUM RATINGS

| SYMBOL | RATING | VALUE | UNIT |
|---------------------|------------------------------------|--|------|
| V _{DD} | Power Supply Voltage | - 0.5 to 4.6 | V |
| V_{DDQ} | Output Buffer Power Supply Voltage | -0.5 to $V_{DD} + 0.5$ (≤ 4.6 V max) | ٧ |
| V _{IN} | Input Terminal Voltage | -0.5 * to 4.6 | ٧ |
| V _{I/O} | Input/Output Terminal Voltage | $-0.5*$ to $V_{DDQ} + 0.5** (\le 4.6 \text{ V max})$ | V |
| P _D | Power Dissipation | 1.6 | w |
| T _{solder} | Soldering Temperature (10s) | 260 | °C |
| T _{strg} | Storage Temperature | - 65 to 150 | °C |
| T _{opr} | Operating Temperature | - 40 to 85 | °C |

*: $-1.0\,V$ with a pulse width of 20% of $\rm ^tKC(min)$ (3 ns max) **: $\rm V_{DDQ}+1.0\,V$ with a pulse width of 20% of $\rm ^tKC(min)$ (3 ns max)

RECOMMENDED DC OPERATING CONDITIONS (Ta = -40° to 85°C)

| SYMBOL | PARAMETER | MIN | TYP. | MAX | UNIT |
|------------------|--|-----------------------|----------|-------------------------|------|
| V _{DD} | Power Supply Voltage | 3.135 | 3.3 | 3.465 | V |
| V_{DDQ} | Output Buffer Power Supply Voltage | 3.135 | 3.3 | 3.465 | V |
| V _{IH} | Input High Voltage | 2.0 | ı | V _{DD} + 0.3** | V |
| V _{IH1} | Input High Voltage for MODE pin | V _{DD} – 0.3 | V_{DD} | V _{DD} + 0.3 | V |
| V _{IL} | Input Low Voltage | - 0.3 * | ı | 0.8 | V |
| V _{IL1} | Input Low Voltage for MODE and NU pins | - 0.3 | 0.0 | 0.3 | V |

*: -0.7 V with a pulse width of 20% of $t_{\text{KC}}(\text{min})$ (3 ns max)

**: $V_{DDQ} + 0.7 \text{ V}$ with a pulse width of 20% of $t_{KC}(min)$ (3 ns max)

Note: NU pin must be low or not connected.

You must not apply a voltage of more than 0.8 V to the NU.

<u>DC CHARACTERISTICS</u> (Ta = -40° to 85°C, $V_{DD} = V_{DDQ} = 3.3 \text{ V} \pm 5\%$)

| SYMBOL | PARAMETER | TEST CONDITIONS | | MIN | TYP. | MAX | UNIT |
|--------------------|----------------------------------|---|--------|------------------------|------|--------|------|
| I _{IL} | Input Leakage Current | V _{IN} = 0 to V _{DD} | | – 1 | - | 1 | μΑ |
| I _{NU} | Input Current (NU pin) | V _{IN} = 0 V to 0.3 V | | – 1 | - | 1 | μΑ |
| I _{LO} | Output Leakage Current | Device Deselected or Output Deselected, $V_{OUT} = 0$ to V_{DDQ} | | – 1 | - | 1 | μΑ |
| ., | Outout High Valtage | $I_{OH} = -8 \text{ mA}$ | | 2.4 | _ | - | |
| V _{OH} | Output High Voltage | I _{OH} = - 100 μA | | V _{DDQ} – 0.2 | _ | _ | v |
| ., | Outnot Low Voltage | I _{OL} = 8 mA | | _ | - | 0.4 | |
| V _{OL} | Output Low Voltage | $I_{OL} = 100 \mu\text{A}$ | | - | - | 0.2 | |
| I _{DDO1} | Operating Current | $I_{OUT} = 0 \text{ mA}, \text{ all inputs} = V_{DD} - 0.2 \text{ V}/0.2 \text{ V}$ | 150MHz | - | _ | 390 mA | |
| וסטטי | operating current | Clock≧t _{KC} (min) | 133MHz | _ | - | 370 | |
| | Operating Current | Device Deselected | 150MHz | - | _ | 180 | 4 |
| I _{DDO2} | (idle) | $I_{OUT} = 0$ mA, all inputs = $V_{DD} - 0.2$ V/0.2 V Clock \ge t _{KC} (min) | 133MHz | - | - | 150 | mA |
| I _{DDS1} | Standby Current (TTL level) | Clock = V _{SS} , all inputs = V _{IH} or V _{IL} | | - | - | 65 | mA |
| I _{DD\$2} | Standby Current (MOS level) | Clock = V_{SS} , all inputs = $V_{DD} - 0.2 V$ or $0.2 V$ | ′ | - | - | 10 | mA |
| I _{DD\$3} | Standby Current (Snooze Mode) | $ZZ \ge V_{DD} - 0.2 \text{ V}$ all inputs = $V_{DD} - 0.2 \text{ V}$ or 0.2 V $Clock \ge t_{KC}(min)$ | 1 | - | 20 | mA | |
| I _{DDS4} | Standby Current (CKE Mode) | $\overline{\text{CKE}} \ge \text{V}_{\text{IH}}$ All inputs = $\text{V}_{\text{DD}} - 0.2 \text{ V}$ or 0.2 V $\text{Clock} \ge \text{t}_{\text{KC}}(\text{min})$ | | - | _ | 20 | mA |

Note: Operating Current(I_{DDO1}) is specified with 50% Read cycles and 50% Write cycles.

<u>CAPACITANCE</u> (Ta = 25° C, f = 1.0 MHz)

| SYMBOL | PARAMETER | TEST CONDITION | MAX | UNIT |
|------------------|--|------------------------|-----|------|
| C··· | Input Capacitance | V _{IN} = GND | 7 | pF |
| C _{IN} | Input Capacitance for MODE, ZZ, NU pin | V _{IN} = GND | 10 | pF |
| C _{I/O} | Input/Output Capacitance | V _{I/O} = GND | 9 | pF |

Note: This parameter is periodically sampled and is not 100% tested.

| AC CHARACTERISTICS | $(Ta = -40^{\circ} t)$ | o 85°C, V _{DD} | $= V_{DDO} = 3.3 V \pm 5\%$) |
|---------------------------|------------------------|-------------------------|-------------------------------|
|---------------------------|------------------------|-------------------------|-------------------------------|

| SYMBOL | PARAMETER | TC55VD1 | 618FFI-150 | TC55VD1 | 618FFI-133 | UNIT |
|-------------------|-----------------------------|---------|------------|---------|------------|--------|
| STIVIBOL | PARAIVIETER | MIN | MAX | MIN | MAX | 1 UNII |
| t _{KC} | CLK Cycle Time | 6.6 | - | 7.5 | - | |
| t _{KH} | CLK High Pulse Width | 2.5 | - | 3 | _ | 1 |
| t _{KL} | CLK Low Pulse Width | 2.5 | - | 3 | - | 1 |
| t _{KQV} | CLK High to Output Valid | - | 3.8 | - | 4.2 | 1 |
| t _{KQX} | CLK High to Output Invalid | 1.5 | - | 1.5 | - | 1 |
| t _{KQLZ} | CLK High to Output Low-Z | 1.5 | - | 1.5 | - | 1 |
| t _{KQHZ} | CLK High to Output High-Z | 1.5 | 3.5 | 1.5 | 3.5 | 1 |
| t _{GQV} | OE Low to Output Valid | - | 3.8 | - | 4.2 | 1 |
| t _{GQLZ} | OE Low to Output Low-Z | 1.5 | - | 1.5 | _ | |
| t _{GQHZ} | OE High to Output High-Z | 1.5 | 4 | 1.5 | 4.2 | 1 |
| t _{AS} | Address Setup Time from CLK | 1.5 | - | 1.5 | - |] |
| t _{D\$} | Data Setup Time from CLK | 1.5 | - | 1.5 | - | |
| t _{WS} | WE Setup Time from CLK | 1.5 | - | 1.5 | _ | |
| t _{CES} | CE Setup Time from CLK | 1.5 | - | 1.5 | _ | ns |
| t _{ADVS} | ADV Setup Time from CLK | 1.5 | - | 1.5 | _ | |
| t _{BWS} | BW Setup Time from CLK | 1.5 | - | 1.5 | _ | |
| t _{CKES} | CKE Setup Time from CLK | 1.5 | - | 1.5 | - | |
| t _{AH} | Address Hold Time from CLK | 0.5 | - | 0.5 | - | |
| t _{DH} | Data Hold Time from CLK | 0.5 | - | 0.5 | _ | |
| t _{WH} | WE Hold Time from CLK | 0.5 | - | 0.5 | _ | |
| t _{CEH} | CE Hold Time from CLK | 0.5 | - | 0.5 | _ | |
| t _{ADVH} | ADV Hold Time from CLK | 0.5 | - | 0.5 | _ | |
| t _{BWH} | BW Hold Time from CLK | 0.5 | - | 0.5 | - | |
| t _{CKEH} | CKE Hold Time from CLK | 0.5 | - | 0.5 | - | |
| t _{ZS} | ZZ Standby Time | 5 | - | 5 | - | |
| t _{ZR} | ZZ Recovery Time | 5 | - | 5 | - | |
| t _{ZHZ} | ZZ to Output in High-Z | _ | 2 | _ | 2 | cycle |

AC TEST CONDITIONS

| Input Pulse Level | 3.0 V/0.0 V |
|--|-------------------------------|
| Input Pulse Rise and Fall Time | 1 V/ns(20%/80%) |
| Input Timing Measurement Reference Level | 1.5 V |
| Output Timing Measurement Reference Level | 1.5 V |
| Output Load | As shown in Fig. 1 and Fig. 2 |

Fig. 1 : AC test load

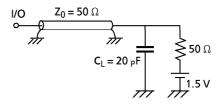
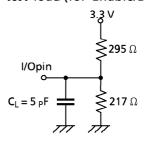


Fig. 2 : AC test load (for Enable/Disable spec)



TIMING DIAGRAMS

READ CYCLE Read Read Read Continue Read Read Continue Continue Deselect Read t_{KC} t_{KH} t_KL **CLK** Address A:1 Α2 **t**ADVH ADV WE BW1 to BW₂ tckes + tckeh **CKE** $\overline{\mathsf{CE}}$ **OE** $\mathsf{t}_{\mathsf{GQV}}$ t_{KQV} t_{KQHZ} t_{KQX} t_{KQX} ‡GQLZ Q1 + 1 I/O Q0 Q1 Q2

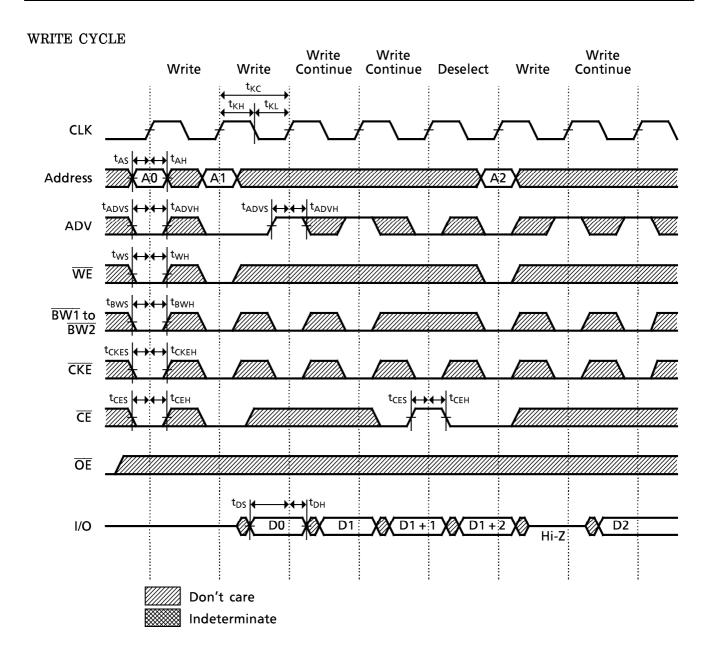
t_{KQLZ}

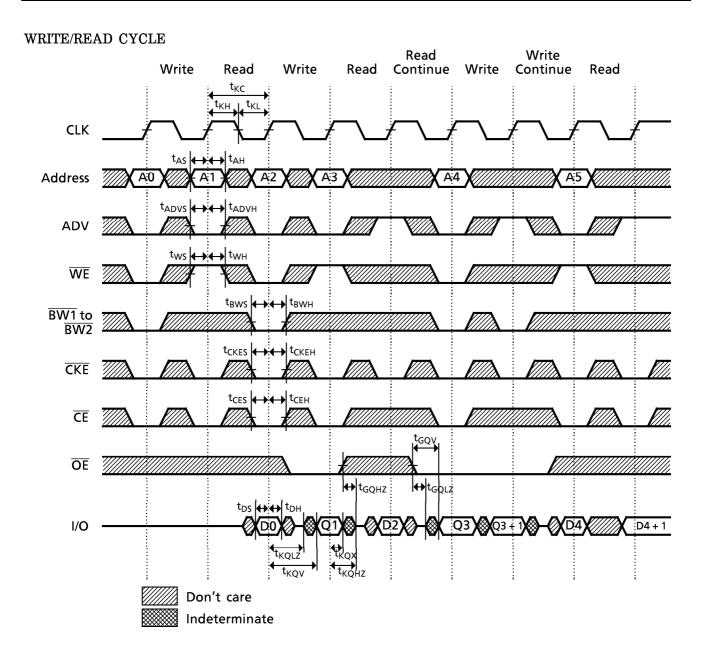
Don't care Indeterminate

t_{KQV}

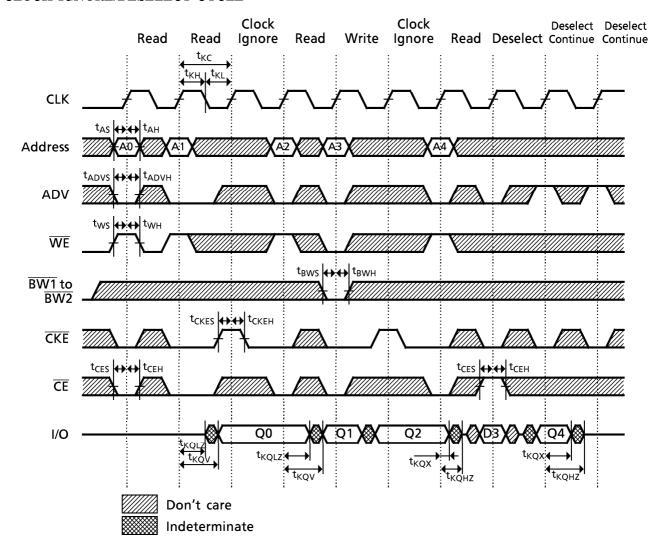
t_{KQLZ}

t_{KQV}

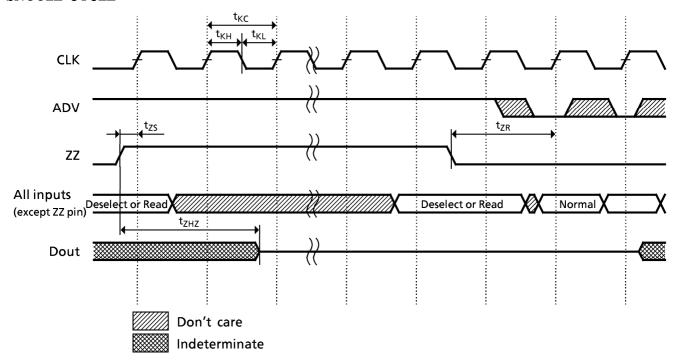




CLOCK IGNORE/DESELECT CYCLE



SNOOZE CYCLE



Notes: 1. The 2 cycles immediately prior to a Snooze brought about by the ZZ pin must be Read or Deselect cycles.

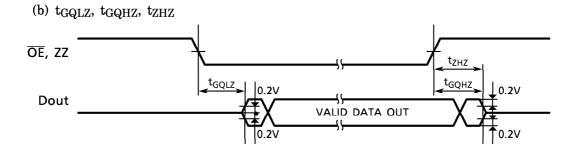
2. Memory data is retained during Snooze cycles.

NOTE: 1. Do not apply opposite data polarity to the I/O pins when they are in the output state.

- 2. Output enable and output disable times are specified as follows using the output load shown in Fig. 1.

Note:

- 1. Input states are defined in the Synchronous Input Truth Table.
- 2. If the device was previously deselected, when the device is selected, the output remains in a high impedance state in the present clock cycle regardless of \overline{OE} because of the output enable delay register. Valid data appears in the second clock cycle when \overline{OE} is low.
- 3. When the device is deselected, the output goes into a high impedance state in the next clock cycle regardless of \overline{OE} .



■ V_{DDQ} = 2.5V Interface specification

RECOMMENDED DC OPERATING CONDITIONS (Ta = -40° to 85°C)

| SYMBOL | PARAMETER | MIN | TYP. | MAX | UNIT | |
|------------------|---|-----------------------|-----------------|---------------------------|------|--|
| V_{DD} | Power Supply Voltage | 3.135 | 3.3 | 3.465 | V | |
| V_{DDQ} | Output Buffer Power Supply Voltage | 2.375 | 2.5 | 2.9 | ٧ | |
| | Input High Voltage for Address and Control pins | 1.7 | _ | V _{DD} + 0.3** | V | |
| V_{IH} | Input High Voltage for I/O pins | 1.7 | - | V _{DDQ} + 0.3*** | | |
| V _{IH1} | Input High Voltage for MODE pin | V _{DD} – 0.3 | V _{DD} | V _{DD} + 0.3 | V | |
| V _{IL} | Input Low Voltage | - 0.3 * | _ | 0.7 | V | |
| V_{IL1} | Input Low Voltage for MODE and NU pins | - 0.3 | 0.0 | 0.3 | V | |

NOTE: NU pin must be low or not connected.

You must not apply a voltage of more than 0.8 V to the NU.

DC CHARACTERISTICS (Ta = -40° to 85° C, $V_{DD} = 3.3 \text{ V} \pm 5\%$, $V_{DDO} = 2.375 \text{ V}$ to 2.9 V)

| SYMBOL | PARAMETER | TEST CONDITIONS | MIN | TYP. | MAX | UNIT | |
|------------------------|--|--|------------------------|------|-----|-------|----|
| I _{IL} | Input Leakage Current | V _{IN} = 0 to V _{DD} | – 1 | - | 1 | μΑ | |
| I _{NU} | Input Current (NU pin) | V _{IN} = 0 V to 0.3 V | – 1 | _ | 1 | μΑ | |
| I _{LO} | Output Leakage Current | Device Deselected or Output Deselected, V _{OUT} = 0 to V _{DDQ} | – 1 | _ | 1 | μΑ | |
| ., | Outroot High Walterna | I _{OH} = -1 mA | | 2.0 | - | _ | |
| V _{OH} | Output High Voltage | $I_{OH} = -100 \mu\text{A}$ | V _{DDQ} – 0.2 | - | _ |] , [| |
| V Contract Law Valtage | | I _{OL} = 1 mA | | - | - | 0.4 | ' |
| V _{OL} | Output Low Voltage | $I_{OL} = 100 \mu A$ | | - | - | 0.2 | |
| | | $I_{OUT} = 0 \text{ mA}$, all inputs = $V_{DD} - 0.2 \text{ V}/0.2 \text{ V}$ | 150MHz | _ | _ | 390 | |
| I _{DDO1} | Operating Current | Clock≧t _{KC} (min) | | - | - | 370 | mA |
| | Operating Current | Device Deselected | 150MHz | - | _ | 180 | |
| IDDO2 | I _{DDO2} (idle) I _{OUT} = 0 mA, all inputs = $V_{DD} - 0.2 V_{DD}$ Clock \ge t _{KC} (min) | | 133MHz | - | _ | 150 | mA |
| I _{DDS2} | Standby Current (MOS level) | Clock = V_{SS} , all inputs = $V_{DD} - 0.2 V$ or 0.2 V | - | _ | 10 | mA | |
| I _{DDS3} | Standby Current (Snooze Mode) | $ZZ \ge V_{DD} - 0.2 \text{ V}$ all inputs = $V_{DD} - 0.2 \text{ V}$ or 0.2 V $Clock \ge t_{KC}(min)$ | - | - | 20 | mA | |
| I _{DDS4} | Standby Current (CKE Mode) | | - | _ | 20 | mA | |

Note: Operating Current(I_{DDO1}) is specified with 50% Read cycles and 50% Write cycles.

| <u>AC CHARACTERISTICS</u> (Ta = -40° to 85°C, $V_{DD} = 3.3 \text{ V} \pm 5\%$, $V_{DDO} = 2.375 \text{ V}$ to 2.9 V | AC CHARACTERISTICS | $(Ta = -40^{\circ} \text{ to } 85^{\circ}C,$ | $V_{DD} = 3.3 V \pm 5\%$ | $V_{DDO} = 2.375 \text{ V to } 2.9 \text{ V}$ |
|--|--------------------|--|--------------------------|---|
|--|--------------------|--|--------------------------|---|

| SYMBOL | TC55VD1618FFI-150 | | 518FFI-150 | TC55VD1618FFI-133 | | UNIT |
|-------------------|-----------------------------|-----|------------|-------------------|-----|--------|
| STIVIBUL | PARAMETER | MIN | MAX | MIN | MAX | - UNII |
| t _{KC} | CLK Cycle Time | 6.6 | - | 7.5 | _ | |
| t _{KH} | CLK High Pulse Width | 2.5 | - | 3 | - | 1 |
| t _{KL} | CLK Low Pulse Width | 2.5 | - | 3 | - | 1 |
| t _{KQV} | CLK High to Output Valid | - | 3.8 | _ | 4.2 | |
| t _{KQX} | CLK High to Output Invalid | 1.5 | - | 1.5 | _ | 1 |
| t _{KQLZ} | CLK High to Output Low-Z | 1.5 | - | 1.5 | _ |] |
| t _{KQHZ} | CLK High to Output High-Z | 1.5 | 3.5 | 1.5 | 3.5 | |
| t _{GQV} | OE Low to Output Valid | - | 3.8 | - | 4.2 | 1 |
| t _{GQLZ} | OE Low to Output Low-Z | 1.5 | _ | 1.5 | _ | 1 |
| t _{GQHZ} | OE High to Output High-Z | 1.5 | 4 | 1.5 | 4.2 | 1 |
| t _{AS} | Address Setup Time from CLK | 1.5 | - | 1.5 | _ |] |
| t _{DS} | Data Setup Time from CLK | 1.5 | - | 1.5 | - | 1 |
| t _{WS} | WE Setup Time from CLK | 1.5 | - | 1.5 | _ | |
| t _{CES} | CE Setup Time from CLK | 1.5 | - | 1.5 | _ | ns |
| t _{ADVS} | ADV Setup Time from CLK | 1.5 | - | 1.5 | _ | 1 |
| t _{BWS} | BW Setup Time from CLK | 1.5 | - | 1.5 | _ |] |
| t _{CKES} | CKE Setup Time from CLK | 1.5 | - | 1.5 | _ | |
| t _{AH} | Address Hold Time from CLK | 0.5 | - | 0.5 | _ | |
| t _{DH} | Data Hold Time from CLK | 0.5 | - | 0.5 | _ | |
| t _{WH} | WE Hold Time from CLK | 0.5 | - | 0.5 | _ | 1 |
| t _{CEH} | CE Hold Time from CLK | 0.5 | - | 0.5 | _ | 1 |
| t _{ADVH} | ADV Hold Time from CLK | 0.5 | - | 0.5 | _ | |
| t _{BWH} | BW Hold Time from CLK | 0.5 | - | 0.5 | _ | |
| t _{CKEH} | CKE Hold Time from CLK | 0.5 | - | 0.5 | _ | |
| t _{ZS} | ZZ Standby Time | 5 | - | 5 | _ |] |
| t _{ZR} | ZZ Recovery Time | 5 | - | 5 | _ | 1 |
| t _{ZHZ} | ZZ to Output in High-Z | - | 2 | - | 2 | cycle |

AC TEST CONDITIONS

| Input Pulse Level | 2.5 V/0.0 V | | |
|--|-------------------------------|--|--|
| Input Pulse Rise and Fall Time | 1 V/ns(20%/80%) | | |
| Input Timing Measurement Reference Level | 1.25 V | | |
| Output Timing Measurement Reference Level | 1.25 V | | |
| Output Load | As shown in Fig. 1 and Fig. 2 | | |

Fig. 1 : AC test load

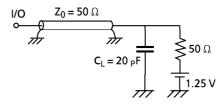
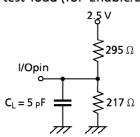
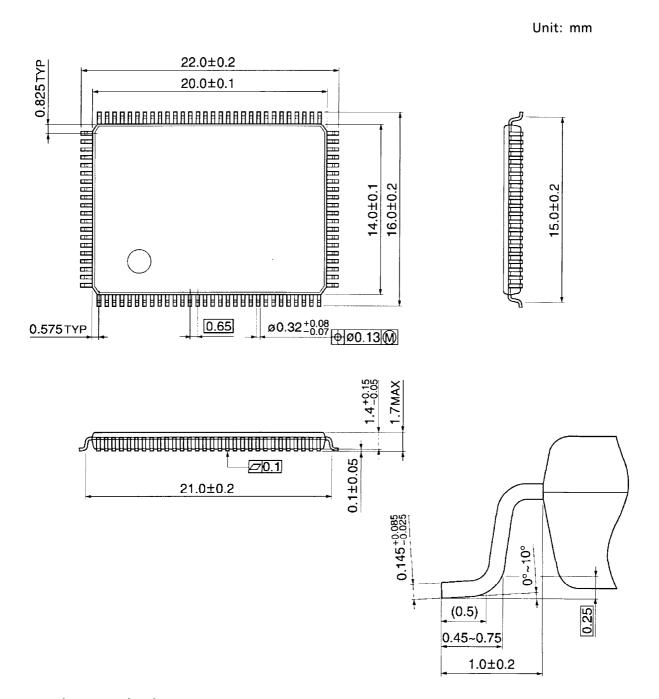


Fig. 2 : AC test load (for Enable/Disable spec)



PACKAGE DIMENSIONS

Plastic LQFP (LQFP100-P-1420-0.65B)



Weight: 0.91 g (typ.)